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Atty. Dkt. No. 040301-0578

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Nobutoshi AOKI et al.

Title: SEMICONDUCTOR INTEGRATED CIRCUIT INCLUDING  
INSULATED GATE FIELD EFFECT TRANSISTOR AND  
METHOD OF MANUFACTURING THE SAME

Appl. No.: 09/440,928

Filing Date: 11/16/1999

Examiner: S. Rao

Art Unit: 2814

Allowed: 08/12/2003

23rd Htre  
1449  
11/25/03  
Rao

REQUEST FOR INITIALED SB/08

Commissioner for Patents  
PO Box 1450  
Alexandria, Virginia 22313-1450

Sir:

In reviewing the above-captioned application file, the undersigned has noted that Applicants' PTO Form SB/08 submitted with their Information Disclosure Statement on June 25, 2003, has not been acknowledged by the Patent and Trademark Office.

The Patent and Trademark Office is, therefore, requested to return the initialed form to the undersigned as soon as possible. A copy of the SB/08 is attached herewith for the Examiner's convenience.

Respectfully submitted,

Date 9/4/03By RLS 34371FOLEY & LARDNER  
Customer Number: 22428

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